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Spatially resolved transport spectroscopy of few donor clusters in silicon

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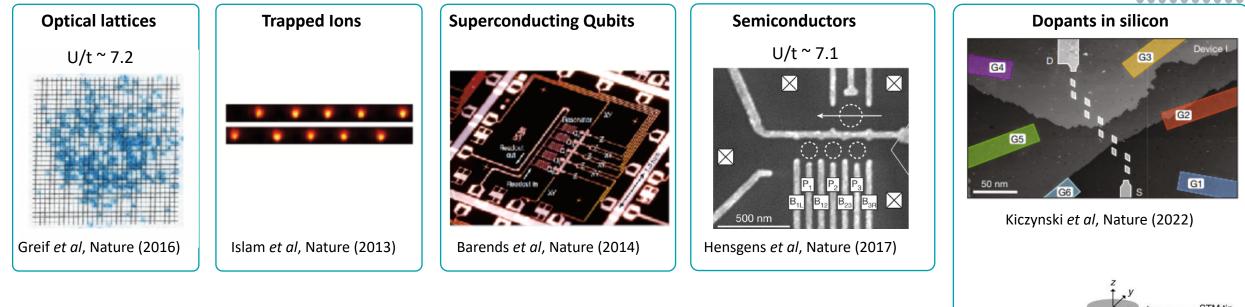
24th Australian Institute of Physics congress

Quantum Simulation

Various platforms for quantum simulation

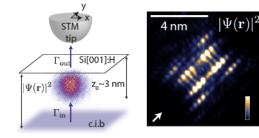
Each platforms has its own advantages and limitations





For **donors** in silicon (in STM):

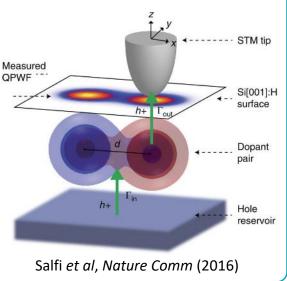
- strong coupling t
- Iow interaction strength U/t ~ 3.5, donors U~50 meV
- Quantum state imaging available = insights on valley & coupling



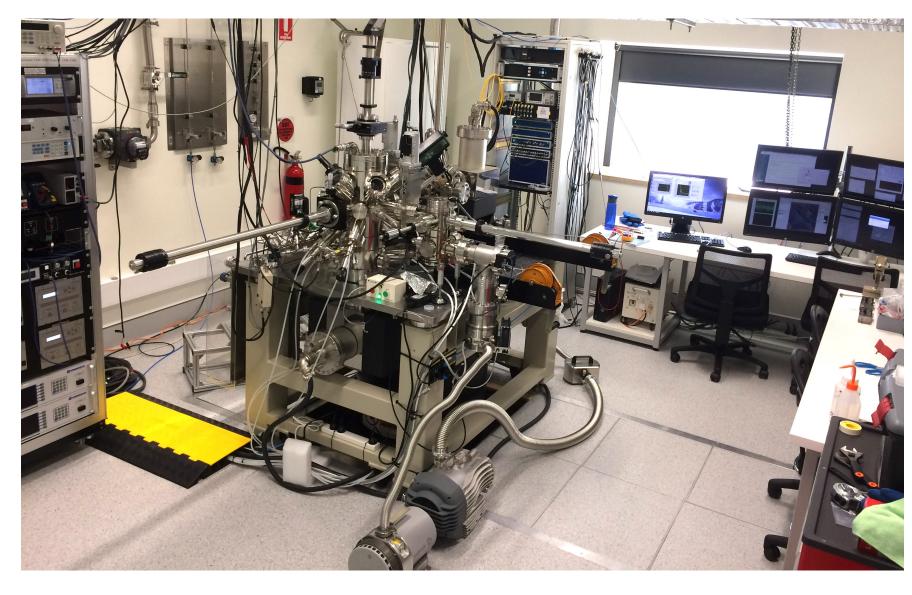
Salfi *et al, Nature Mat* (2014) Voisin *et al, Nature Comm* (2020) M. Usman *et al, Nature Nano* (2016)

- No spin degree of freedom so far.
- No engineered sites,

(previous sample dopants randomly distributed)



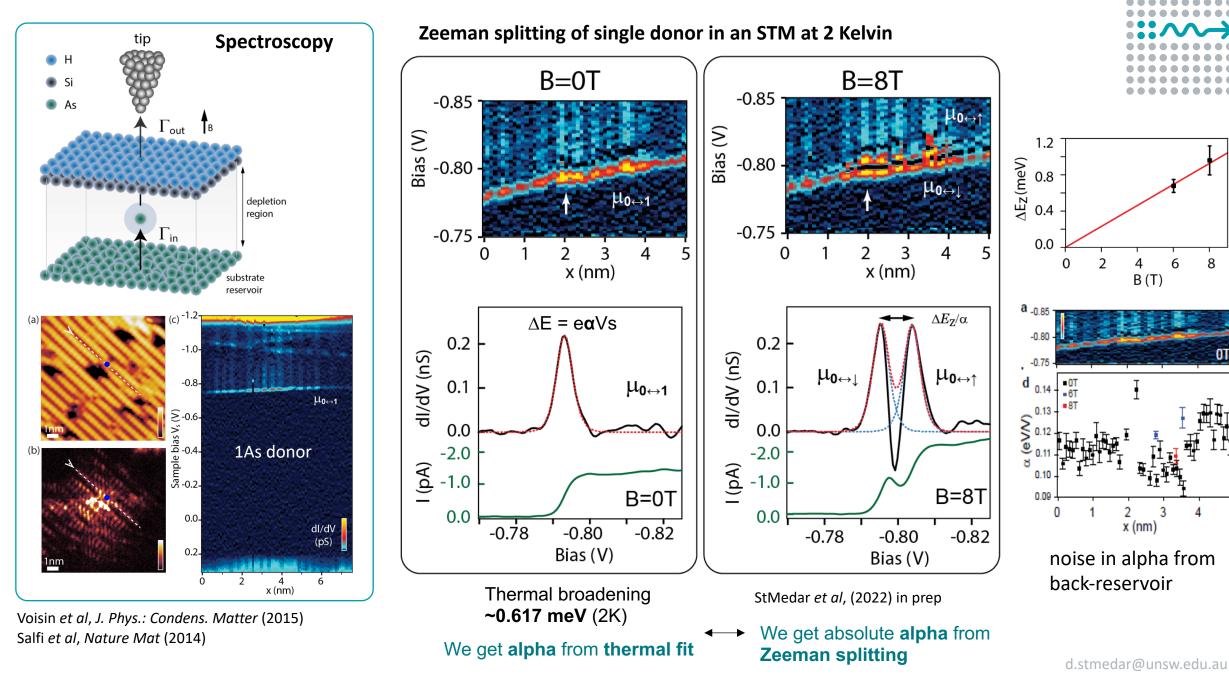
Unisoku STM @ UNSW





The lab

Spatially resolved magneto spectroscopy of a single donor

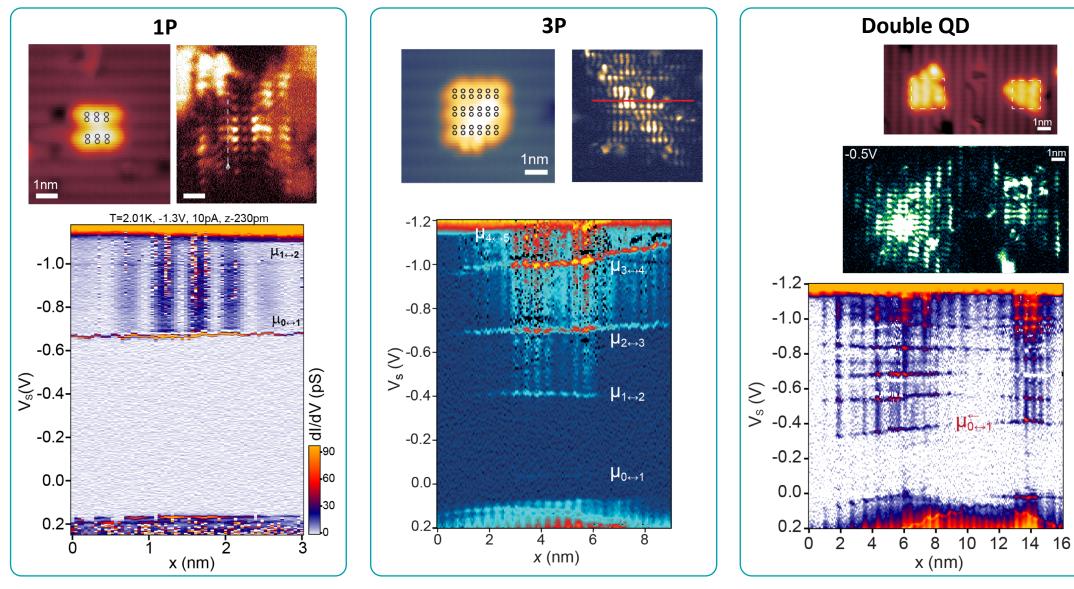


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Spectroscopy of engineered few-donor Si:P quantum dots

Motivation: Characterize the building blocks of a dopant based analog quantum simulator.

Engineered few donors quantum dots



::~~→

Capacitive Transport model To understand the electronic transitions + charging energies

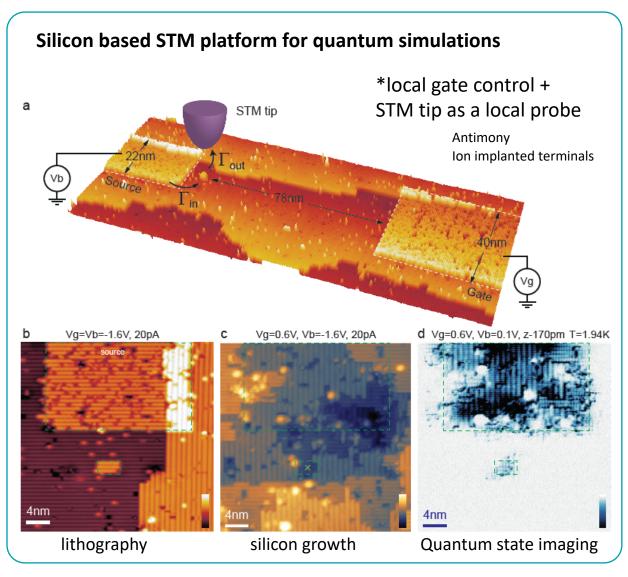
1.5

l (pA)

0.5

StMedar et al, (2022) in prep

Multi-terminal Si:P STM devices



e.g. 3P quantum dot (2K) I (pA) С z-240pm 0e 🛶 1e 0.12-0.08-0.04-0.00-2e0e1e3e -0.04 1e ↔ 2e -0.08 -0.12d 0.12 0.08 T=1.93 2e 🛶 3e z-240p 0.04 0.00--0.04--0.08--0.12 -1.2 -1.0 -0.8 -0.6 -0.4 -0.2 0.0 0.2 0.4 0.6 0.8 $V_{g}(V)$ H dl/dV (pS) 04 Wave function mapping Access to excited states + at different filling factors theory to understand interactions in these QD Rahman group @UNSW

Voisin *et al*, submitted StMedar *et al*, (2022), in prep

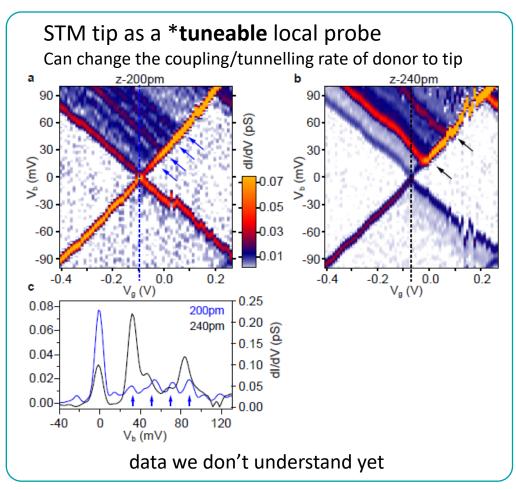
Multi-terminal Si:P STM devices

Charging energies close to bulk

good agreement between experiments and existing literature

	3P	Weber, Nature Tech (2014	*Weber,) Phd thesis (2013)	Ye, Nature (2019)	Back-reservoir †
$E_{\rm C_1} [{\rm meV}]$	95 ± 3	92 ± 5	95.1	90 ± 18.5	19.1
$E_{\rm C_2} [{\rm meV}]$	81 ± 3	75 ± 5	53.6		15.1
$E_{\rm C_3}$ [meV]	66 ± 3	66 ± 5	43		15.9
	4	Р	Voisin, submitted	Webe Nature	r, • Tech (2014)
$E_{\rm C_1} [{\rm meV}]$	- 13	33 ± 3	130 ± 5	133.9)
$E_{\rm C_2} [{\rm meV}]$	80	0 ± 3		81.2	
$E = [m \circ V]$	55	5 ± 3		70.2	
$E_{\mathrm{C}_3} \; [\mathrm{meV}]$					

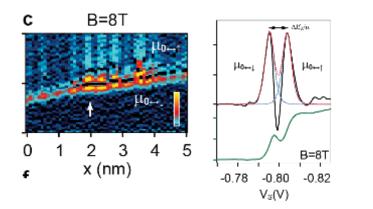
Excited states spectroscopy



Conclusion

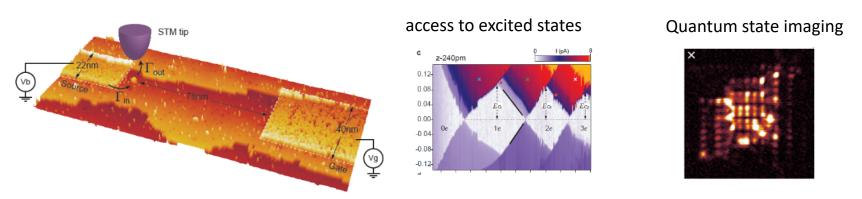
We showed in an STM experiments:

(1) Access to the spin degree of freedom (resolution of single donor)





(2) Local gate control and in-situ spectroscopy of few donor quantum dots



Towards spin-based quantum simulation with dopants in silicon, with the STM tip as local spectral function probe. e.g. mapping of exotic ground states of matter away from half-filling.



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Theory (donor cluster simulation) A M Saffat-Ee Huq and Rajib Rahman (UNSW)

Theory (quantum simulation) David Mikhail and Stephan Rachel (University of Melbourne)

Sb Ion implantation Brett Johnson and Jeffrey McCallum (University of Melbourne)





THANK YOU

Cleanroom Facility Australian National Fabrication Facility NSW Node (UNSW)



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